

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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BIPOLAR ANALOG INTEGRATED CIRCUIT  
 **$\mu$ PC8172TB**

SILICON MMIC 2.5 GHz FREQUENCY UP-CONVERTER  
 FOR WIRELESS TRANSCEIVER

**DESCRIPTION**

The  $\mu$ PC8172TB is a silicon monolithic integrated circuit designed as frequency up-converter for wireless transceiver transmitter stage. This IC is manufactured using NEC's 30 GHz  $f_{max}$ . UHS0 (Ultra High Speed Process) silicon bipolar process.

This IC is as same circuit current as conventional  $\mu$ PC8106TB, but operates at higher frequency, higher gain and lower distortion. Consequently this IC is suitable for mobile communications.

**FEATURES**

- Recommended operating frequency :  $f_{RFout} = 0.8$  to 2.5 GHz
- Higher  $IP_3$  :  $CG = 9.5$  dB TYP.,  $OIP_3 = +7.5$  dBm TYP. @  $f_{RFout} = 0.9$  GHz
- High-density surface mounting : 6-pin super minimold package
- Supply voltage :  $V_{CC} = 2.7$  to 3.3 V

**APPLICATIONS**

- PCS1900M
- 2.4 GHz band transmitter/receiver system (wireless LAN etc.)

**ORDERING INFORMATION**

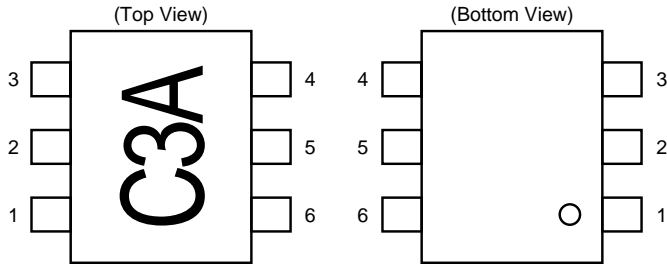
Part Number	Package	Marking	Supplying Form
$\mu$ PC8172TB-E3	6-pin super minimold	C3A	<ul style="list-style-type: none"> <li>• Embossed tape 8 mm wide.</li> <li>• Pin 1, 2, 3 face the tape perforation side.</li> <li>• Qty 3 kpcs/reel.</li> </ul>

**Remark** To order evaluation samples, please contact your local NEC sales office.  
 (Part number for sample order:  $\mu$ PC8172TB)

**Caution Electro-static sensitive devices**

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 Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

**PIN CONNECTIONS**



Pin No.	Pin Name
1	IFinput
2	GND
3	LOinput
4	PS
5	V <sub>CC</sub>
6	RFoutput

**SERIES PRODUCTS (T<sub>A</sub> = +25°C, V<sub>CC</sub> = V<sub>RFout</sub> = 3.0 V, Z<sub>s</sub> = Z<sub>L</sub> = 50 Ω)**

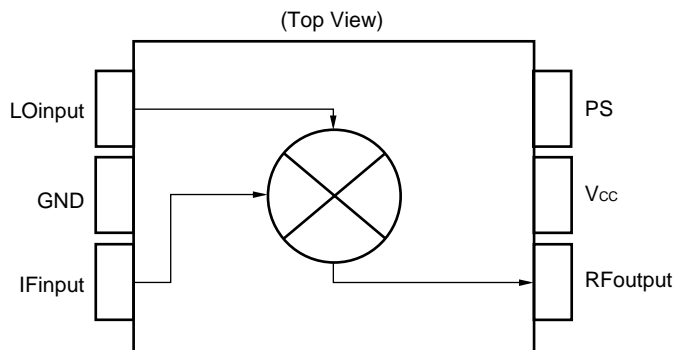
Part Number	I <sub>CC</sub> (mA)	f <sub>RFout</sub> (GHz)	CG (dB)		
			@RF 0.9 GHz <sup>Note</sup>	@RF 1.9 GHz	@RF 2.4 GHz
μPC8172TB	9	0.8 to 2.5	9.5	8.5	8.0
μPC8106TB	9	0.4 to 2.0	9	7	–
μPC8109TB	5	0.4 to 2.0	6	4	–
μPC8163TB	16.5	0.8 to 2.0	9	5.5	–

Part Number	P <sub>O(sat)</sub> (dBm)			OIP <sub>3</sub> (dBm)		
	@RF 0.9 GHz <sup>Note</sup>	@RF 1.9 GHz	@RF 2.4 GHz	@RF 0.9 GHz <sup>Note</sup>	@RF 1.9 GHz	@RF 2.4 GHz
μPC8172TB	+0.5	0	–0.5	+7.5	+6.0	+4.0
μPC8106TB	–2	–4	–	+5.5	+2.0	–
μPC8109TB	–5.5	–7.5	–	+1.5	–1.0	–
μPC8163TB	+0.5	–2	–	+9.5	+6.0	–

**Note** f<sub>RFout</sub> = 0.83 GHz @ μPC8163TB

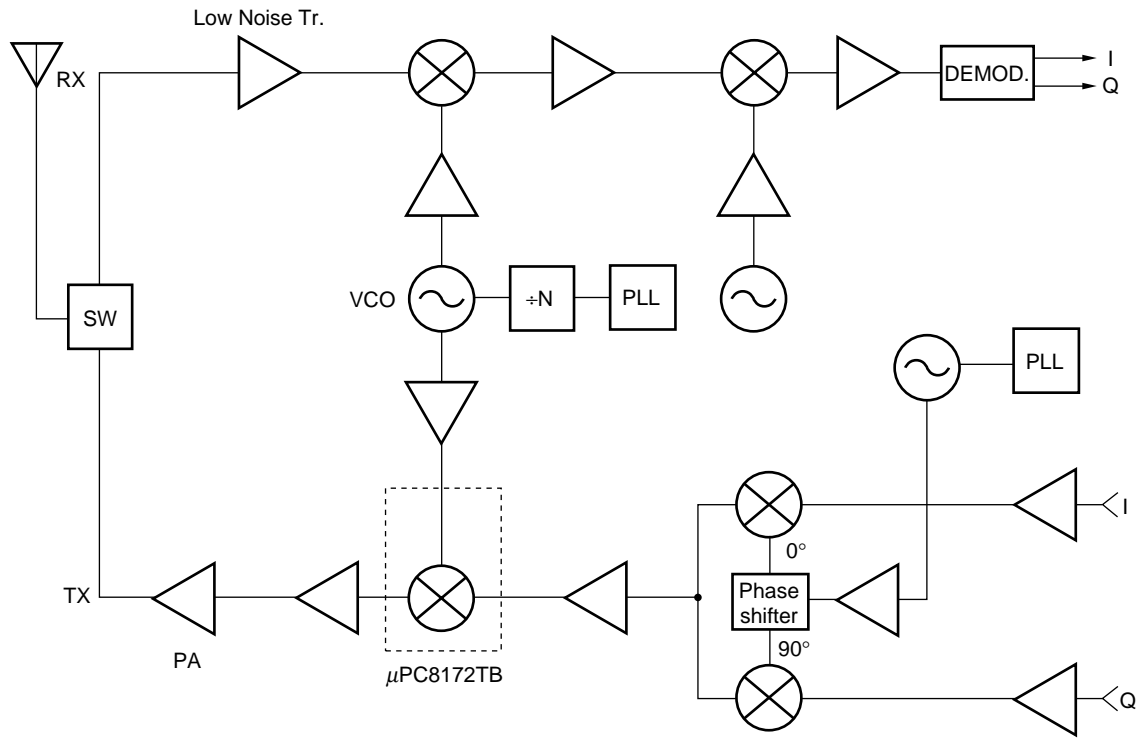
**Remark** Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail.  
To know the associated product, please refer to each latest data sheet.

**BLOCK DIAGRAM (FOR THE μPC8172TB)**



SYSTEM APPLICATION EXAMPLES (SCHEMATICS OF IC LOCATION IN THE SYSTEM)

Wireless Transceiver



To know the associated products, please refer to each latest data sheet.

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1. PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) <sup>Note</sup>	Function and Explanation	Equivalent Circuit						
1	IFinput	–	1.4	This pin is IF input to double balanced mixer (DBM). The input is designed as high impedance. The circuit contributes to suppress spurious signal. Also this symmetrical circuit can keep specified performance insensitive to process-condition distribution. For above reason, double balanced mixer is adopted.							
2	GND	GND	–	GND pin. Ground pattern on the board should be formed as wide as possible. Track Length should be kept as short as possible to minimize ground impedance.							
3	LOinput	–	2.3	Local input pin. Recommendable input level is –10 to 0 dBm.							
5	Vcc	2.7 to 3.3	–	Supply voltage pin.							
6	RFoutput	Same bias as Vcc through external inductor	–	This pin is RF output from DBM. This pin is designed as open collector. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage.							
4	PS	Vcc/GND	–	Power save control pin. Bias controls operation as follows. <table border="1" style="margin: 10px auto;"> <thead> <tr> <th>Pin bias</th> <th>Control</th> </tr> </thead> <tbody> <tr> <td>Vcc</td> <td>Operation</td> </tr> <tr> <td>GND</td> <td>Power Save</td> </tr> </tbody> </table>	Pin bias	Control	Vcc	Operation	GND	Power Save	
Pin bias	Control										
Vcc	Operation										
GND	Power Save										

**Note** Each pin voltage is measured with  $V_{CC} = V_{PS} = V_{RFout} = 3.0\text{ V}$ .

★ 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Rating	Unit
Supply Voltage	V <sub>CC</sub>	T <sub>A</sub> = +25°C	3.6	V
PS pin Input Voltage	V <sub>PS</sub>	T <sub>A</sub> = +25°C	3.6	V
Power Dissipation of Package	P <sub>D</sub>	Mounted on double-side copperclad 50 × 50 × 1.6 mm epoxy glass PWB (T <sub>A</sub> = +85°C)	270	mW
Operating Ambient Temperature	T <sub>A</sub>		−40 to +85	°C
Storage Temperature	T <sub>stg</sub>		−55 to +150	°C
Input Power	P <sub>in</sub>		+10	dBm

3. RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	V <sub>CC</sub>	The same voltage should be applied to pin 5 and 6	2.7	3.0	3.3	V
Operating Ambient Temperature	T <sub>A</sub>		−40	+25	+85	°C
Local Input Level	P <sub>LOin</sub>	Z <sub>s</sub> = 50 Ω (without matching)	−10	−5	0	dBm
RF Output Frequency	f <sub>RFout</sub>	With external matching circuit	0.8	–	2.5	GHz
IF Input Frequency	f <sub>IFin</sub>		50	–	400	MHz

4. ELECTRICAL CHARACTERISTICS

(T<sub>A</sub> = +25°C, V<sub>CC</sub> = V<sub>RFout</sub> = 3.0 V, f<sub>IFin</sub> = 240 MHz, P<sub>LOin</sub> = −5 dBm, and V<sub>PS</sub> ≥ 2.7 V unless otherwise specified)

Parameter	Symbol	Test Conditions <sup>Note</sup>	MIN.	TYP.	MAX.	Unit
Circuit Current	I <sub>CC</sub>	No Signal	5.5	9.0	13	mA
Circuit Current In Power Save Mode	I <sub>CC(PS)</sub>	V <sub>PS</sub> = 0 V	–	–	2	μA
Conversion Gain	CG1	f <sub>RFout</sub> = 0.9 GHz, P <sub>IFin</sub> = −30 dBm	6.5	9.5	12.5	dB
	CG2	f <sub>RFout</sub> = 1.9 GHz, P <sub>IFin</sub> = −30 dBm	5.5	8.5	11.5	dB
	CG3	f <sub>RFout</sub> = 2.4 GHz, P <sub>IFin</sub> = −30 dBm	5	8.0	11.0	dB
Saturated RF Output Power	P <sub>O(sat)1</sub>	f <sub>RFout</sub> = 0.9 GHz, P <sub>IFin</sub> = 0 dBm	−2.5	+0.5	–	dBm
	P <sub>O(sat)2</sub>	f <sub>RFout</sub> = 1.9 GHz, P <sub>IFin</sub> = 0 dBm	−3.5	0	–	dBm
	P <sub>O(sat)3</sub>	f <sub>RFout</sub> = 2.4 GHz, P <sub>IFin</sub> = 0 dBm	−4	−0.5	–	dBm

**Note** f<sub>RFout</sub> < f<sub>LOin</sub> @ f<sub>RFout</sub> = 0.9 GHz

f<sub>LOin</sub> < f<sub>RFout</sub> @ f<sub>RFout</sub> = 1.9 GHz/2.4 GHz



**5. OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY**

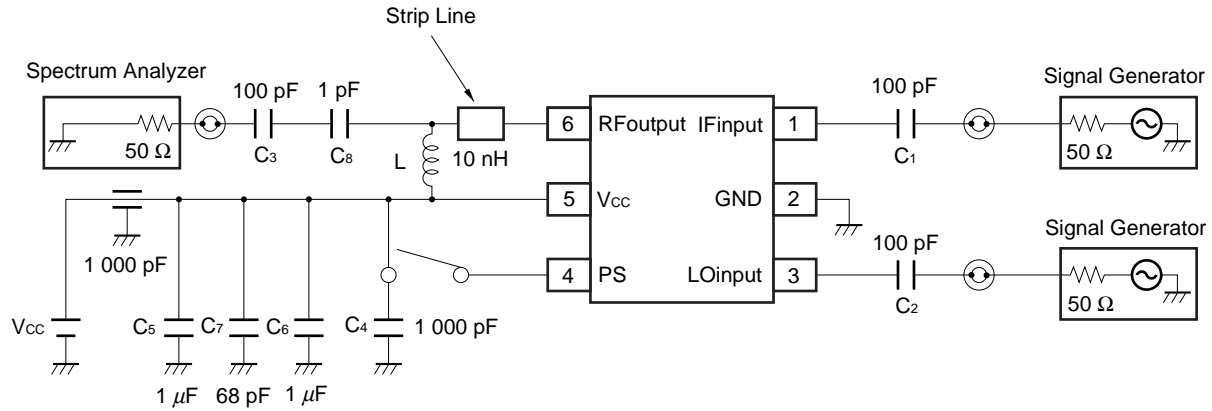
(T<sub>A</sub> = +25°C, V<sub>CC</sub> = V<sub>RFout</sub> = 3.0 V, P<sub>LOin</sub> = -5 dBm, and V<sub>PS</sub> ≥ 2.7 V unless otherwise specified)

Parameter		Symbol	Test Conditions <sup>Note</sup>	Data	Unit
Output Third-Order Distortion Intercept Point		OIP <sub>31</sub>	f <sub>RFout</sub> = 0.9 GHz	+7.5	dBm
		OIP <sub>32</sub>	f <sub>RFout</sub> = 1.9 GHz		
		OIP <sub>33</sub>	f <sub>RFout</sub> = 2.4 GHz		
			f <sub>Fin1</sub> = 240 MHz f <sub>Fin2</sub> = 241 MHz	+6.0	dBm
				+4.0	dBm
Input Third-Order Distortion Intercept Point		IIP <sub>31</sub>	f <sub>RFout</sub> = 0.9 GHz	-2.0	dBm
		IIP <sub>32</sub>	f <sub>RFout</sub> = 1.9 GHz		
		IIP <sub>33</sub>	f <sub>RFout</sub> = 2.4 GHz		
			f <sub>Fin1</sub> = 240 MHz f <sub>Fin2</sub> = 241 MHz	-2.5	dBm
				-4.0	dBm
SSB Noise Figure		SSB•NF1	f <sub>RFout</sub> = 0.9 GHz, f <sub>Fin</sub> = 240 MHz	9.5	dB
		SSB•NF2	f <sub>RFout</sub> = 1.9 GHz, f <sub>Fin</sub> = 240 MHz	10.4	dB
		SSB•NF3	f <sub>RFout</sub> = 2.4 GHz, f <sub>Fin</sub> = 240 MHz	10.6	dB
Power Save Response Time	Rise time	T <sub>PS(rise)</sub>	V <sub>PS</sub> : GND → V <sub>CC</sub>	1	μs
	Fall time	T <sub>PS(fall)</sub>	V <sub>PS</sub> : V <sub>CC</sub> → GND	1.5	μs

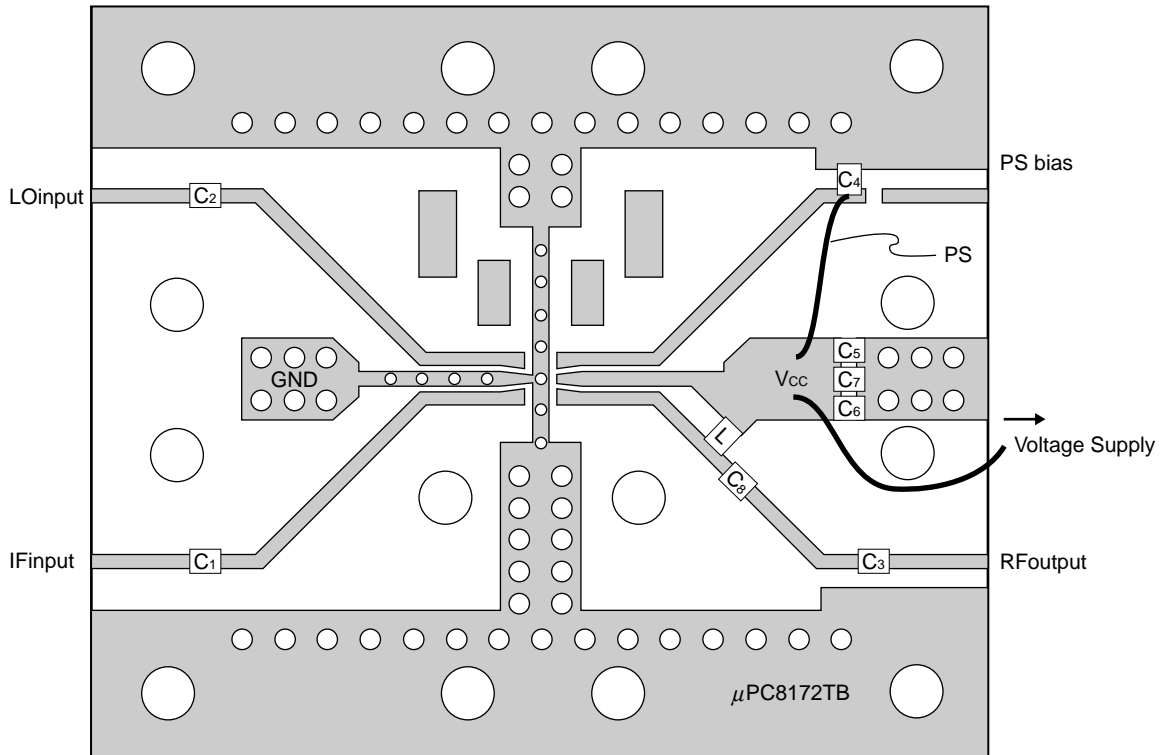
**Note** f<sub>RFout</sub> < f<sub>LOin</sub> @ f<sub>RFout</sub> = 0.9 GHz  
 f<sub>LOin</sub> < f<sub>RFout</sub> @ f<sub>RFout</sub> = 1.9 GHz/2.4 GHz

6. TEST CIRCUIT

★ 6.1 TEST CIRCUIT 1 (f<sub>RFout</sub> = 900 MHz)



EXAMPLE OF TEST CIRCUIT 1 ASSEMBLED ON EVALUATION BOARD



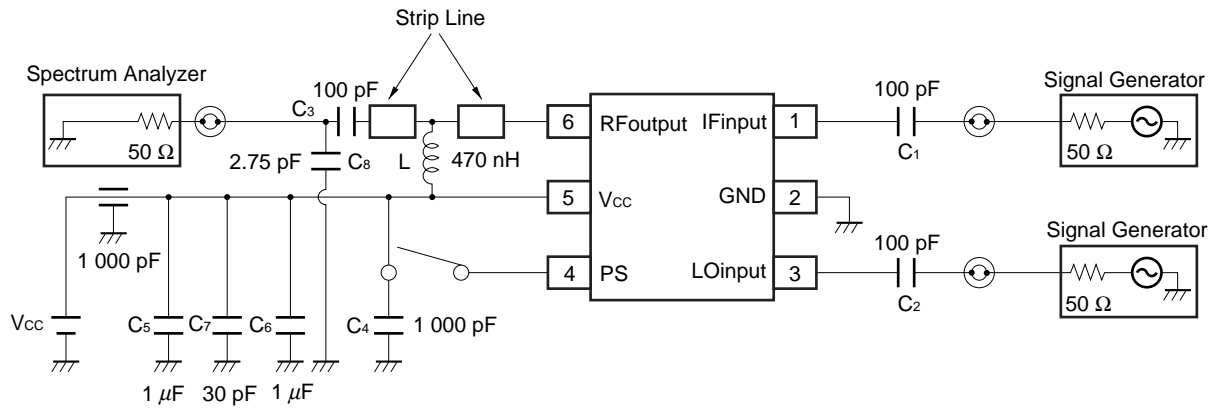
COMPONENT LIST

Form	Symbol	Value
Chip capacitor	C <sub>1</sub> , C <sub>2</sub> , C <sub>3</sub>	100 pF
	C <sub>4</sub>	1 000 pF
	C <sub>5</sub> , C <sub>6</sub>	1 μF
	C <sub>7</sub>	68 pF
	C <sub>8</sub>	1 pF
Chip inductor	L	10 nH <sup>Note</sup>

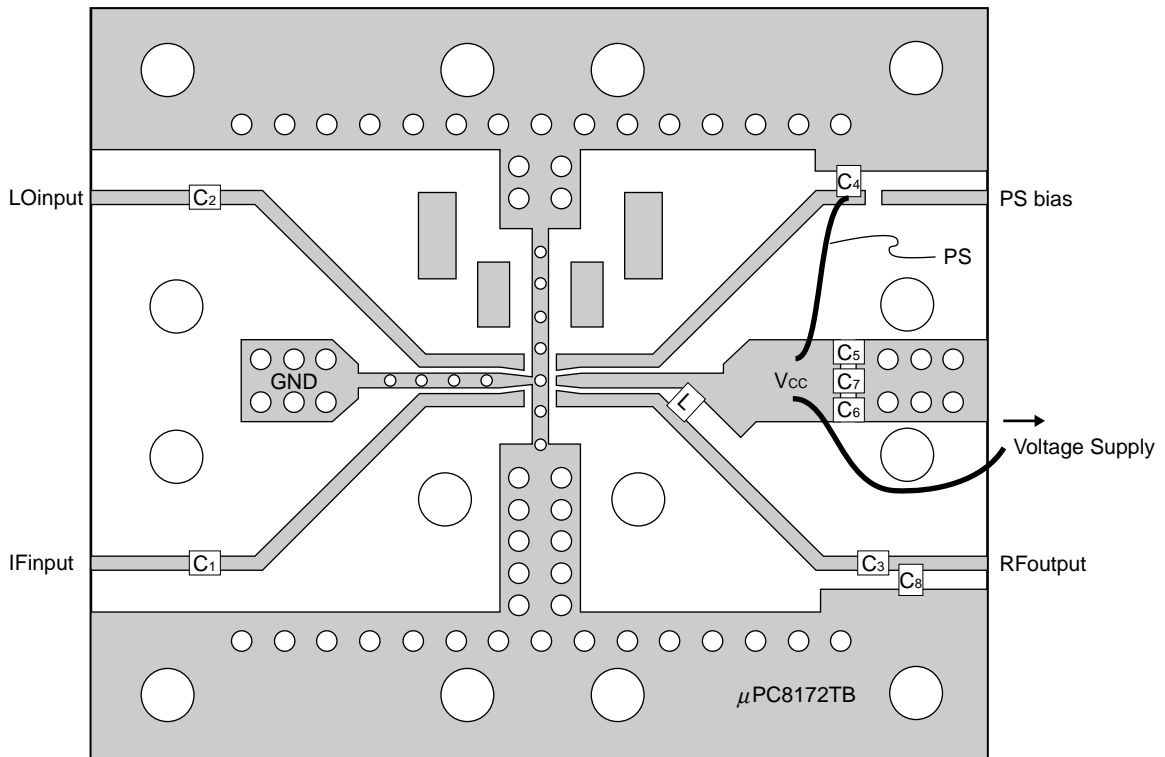
- (\*1) 35 × 42 × 0.4 mm polyimide board, double-sided copper clad
- (\*2) Ground pattern on rear of the board
- (\*3) Solder plated patterns
- (\*4) ○○: Through holes

Note 10 nH: LL1608-FH10N (TOKO Co., Ltd.)

★ 6.2 TEST CIRCUIT 2 ( $f_{RFout} = 1.9\text{ GHz}$ )



EXAMPLE OF TEST CIRCUIT 2 ASSEMBLED ON EVALUATION BOARD



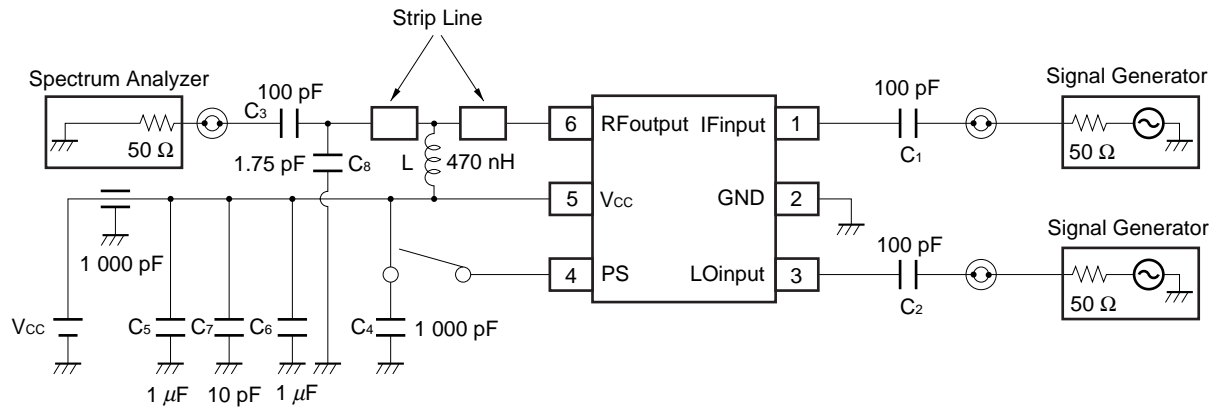
COMPONENT LIST

Form	Symbol	Value
Chip capacitor	C <sub>1</sub> , C <sub>2</sub> , C <sub>3</sub>	100 pF
	C <sub>4</sub>	1 000 pF
	C <sub>5</sub> , C <sub>6</sub>	1 μF
	C <sub>7</sub>	30 pF
	C <sub>8</sub>	2.75 pF
Chip inductor	L	470 nH <sup>Note</sup>

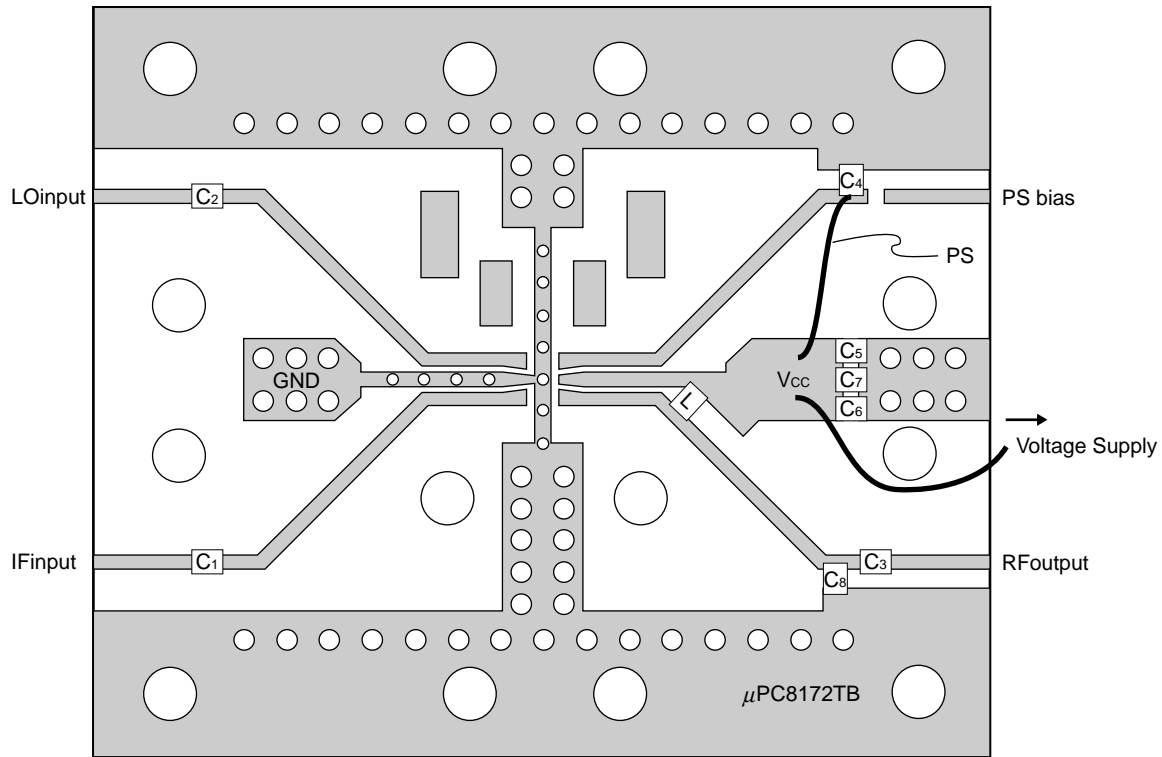
- (\*1) 35 × 42 × 0.4 mm polyimide board, double-sided copper clad
- (\*2) Ground pattern on rear of the board
- (\*3) Solder plated patterns
- (\*4) ○ ○ ○: Through holes

Note 470 nH: LL2012-FR47 (TOKO Co., Ltd.)

★ 6.3 TEST CIRCUIT 3 (f<sub>RFout</sub> = 2.4 GHz)



EXAMPLE OF TEST CIRCUIT 3 ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

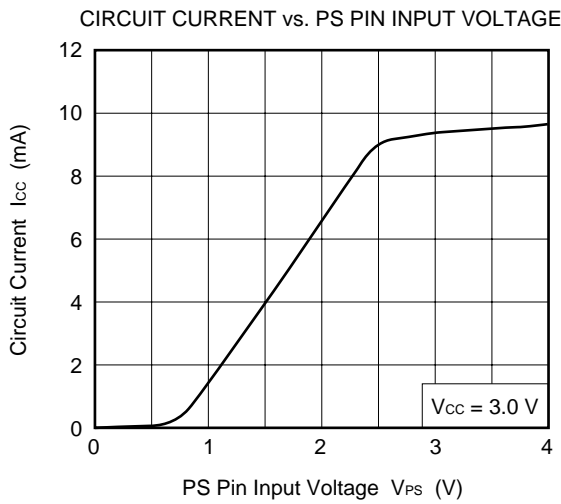
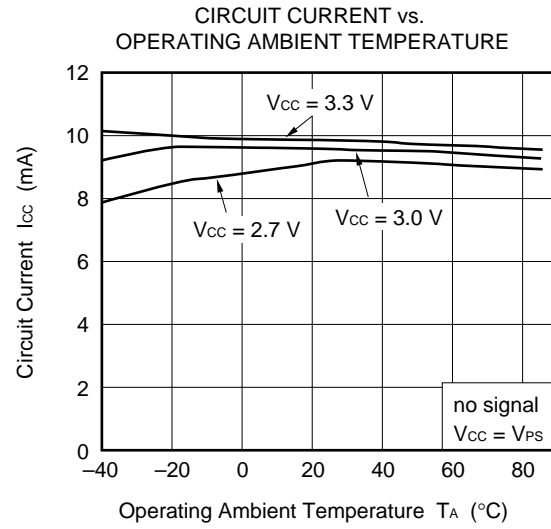
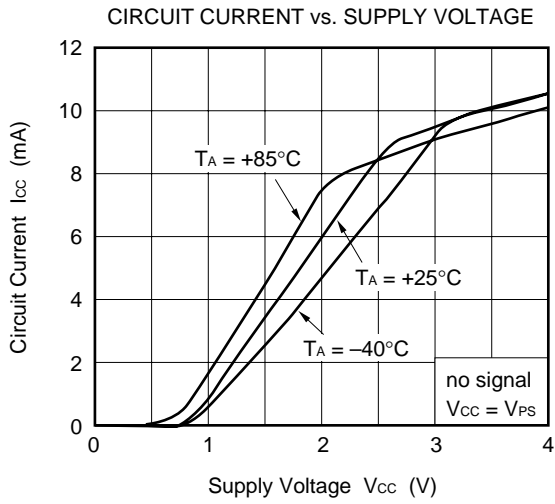
Form	Symbol	Value
Chip capacitor	C <sub>1</sub> , C <sub>2</sub> , C <sub>3</sub>	100 pF
	C <sub>4</sub>	1 000 pF
	C <sub>5</sub> , C <sub>6</sub>	1 μF
	C <sub>7</sub>	10 pF
	C <sub>8</sub>	1.75 pF
	Chip inductor	L

- (\*1) 35 × 42 × 0.4 mm polyimide board, double-sided copper clad
- (\*2) Ground pattern on rear of the board
- (\*3) Solder plated patterns
- (\*4) ○○: Through holes

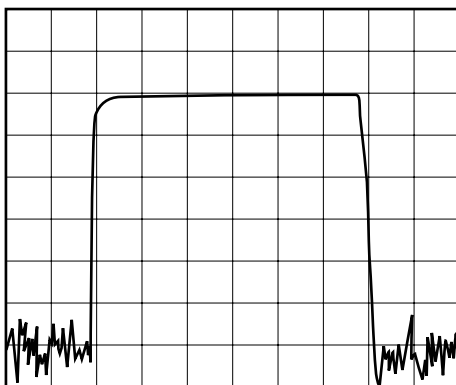
Note 470 nH: LL2012-FR47 (TOKO Co., Ltd.)

**Caution** The test circuits and board pattern on data sheet are for performance evaluation use only (They are not recommended circuits). In the case of actual design-in, matching circuit should be determined using S-parameter of desired frequency in accordance to actual mounting pattern.

★ 7. TYPICAL CHARACTERISTICS (Unless otherwise specified,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = V_{RFout}$ )



PS PIN CONTROL RESPONSE TIME



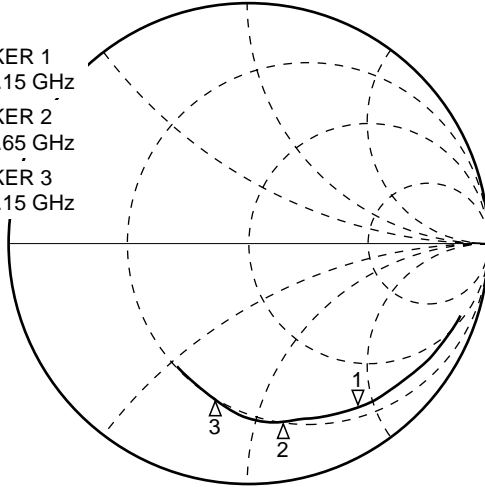
REF LVL = 0 dBm  
 ATT = 10 dB  
 10 dB/DIV (Vertical axis)  
 CENTER = 0.9 GHz  
 SPAN = 0 Hz  
 RBW = 3 MHz  
 VBW = 3 MHz  
 SWP = 50  $\mu\text{sec}$   
 5  $\mu\text{sec}$ /DIV (Horizontal axis)

★ **S-PARAMETERS FOR EACH PORT** ( $V_{CC} = V_{PS} = V_{RFout} = 3.0\text{ V}$ )  
 (The parameters are monitored at DUT pins)

LO port

$S_{11}$  Z  
 REF 1.0 Units  
 1 200.0 mUnits/  
 ▽ 21.625 Ω -91.148 Ω  
 hp

MARKER 1  
 1.15 GHz  
 MARKER 2  
 1.65 GHz  
 MARKER 3  
 2.15 GHz

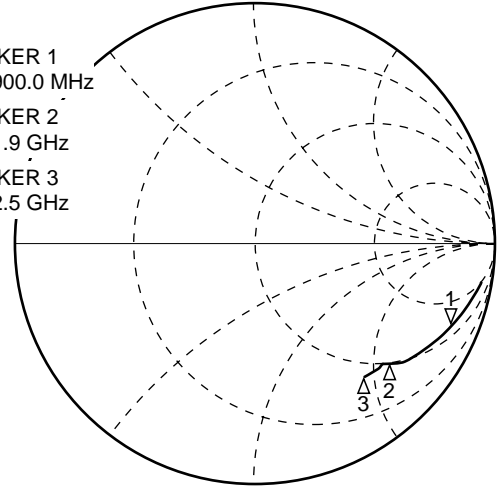


START 0.400000000 GHz  
 STOP 2.500000000 GHz

RF port (without matching)

$S_{22}$  Z  
 REF 1.0 Units  
 1 200.0 mUnits/  
 ▽ 71.5 Ω -240.34 Ω  
 hp

MARKER 1  
 900.0 MHz  
 MARKER 2  
 1.9 GHz  
 MARKER 3  
 2.5 GHz

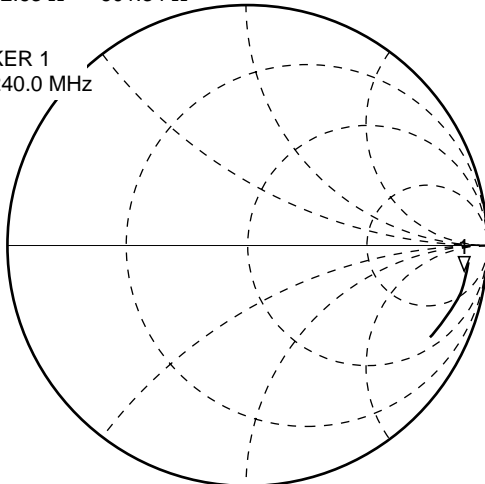


START 0.400000000 GHz  
 STOP 2.500000000 GHz

IF port

$S_{11}$  Z  
 REF 1.0 Units  
 1 200.0 mUnits/  
 ▽ 332.63 Ω -601.34 Ω  
 hp

MARKER 1  
 240.0 MHz

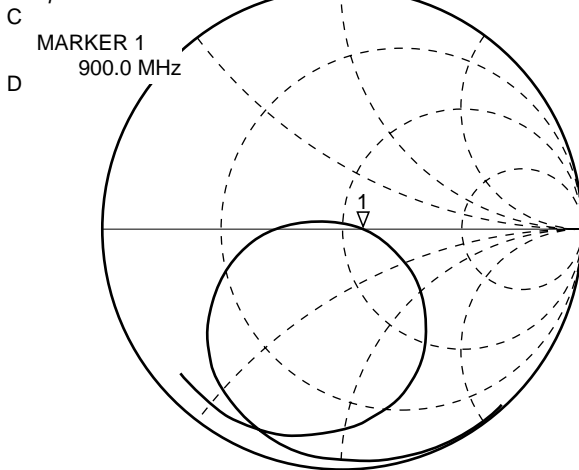


START 0.100000000 GHz  
 STOP 1.000000000 GHz

★ S-PARAMETERS FOR MATCHED RF OUTPUT ( $V_{CC} = V_{PS} = V_{RFout} = 3.0\text{ V}$ ) –ON EVALUATION BOARD–  
 (S22 data are monitored at RF connector on board)

900 MHz (matched in test circuit 1)

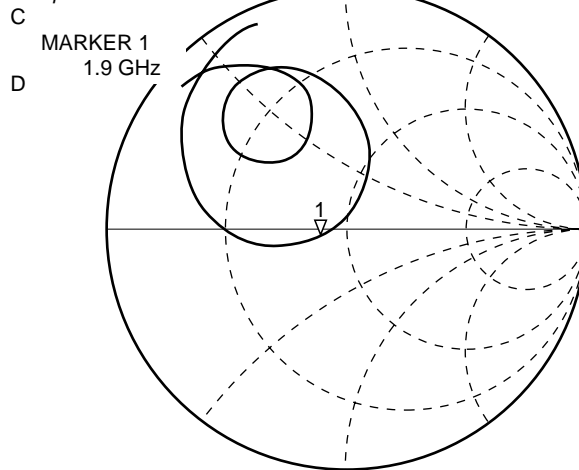
S22 Z  
 REF 1.0 Units  
 1 200.0 mUnits/  
 $\nabla$  55.615  $\Omega$  2.2849  $\Omega$   
 hp



START 0.40000000 GHz  
 STOP 1.40000000 GHz

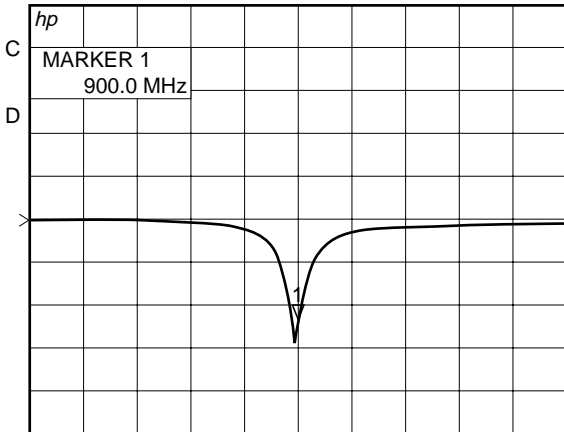
1.9 GHz (matched in test circuit 2)

S22 Z  
 REF 1.0 Units  
 1 200.0 mUnits/  
 $\nabla$  38.584  $\Omega$  -2.2656  $\Omega$   
 hp



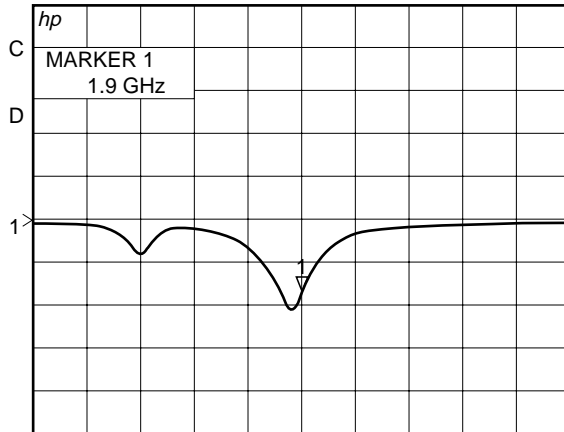
START 1.40000000 GHz  
 STOP 2.40000000 GHz

S22 log MAG.  
 REF 0.0 dB  
 1 10.0 dB/  
 $\nabla$  -24.754 dB  
 hp



START 0.40000000 GHz  
 STOP 1.40000000 GHz

S22 log MAG.  
 REF 0.0 dB  
 1 10.0 dB/  
 $\nabla$  -18.196 dB  
 hp



START 1.40000000 GHz  
 STOP 2.40000000 GHz

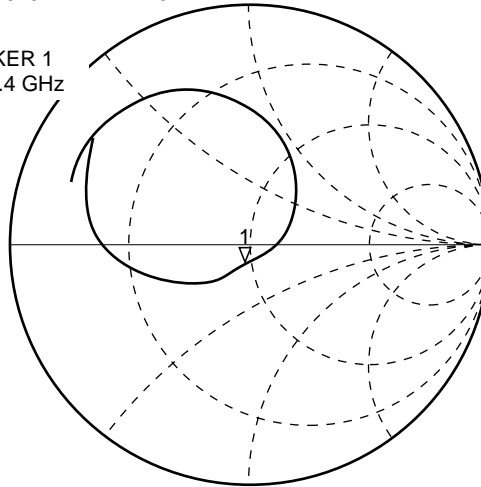


★ **S-PARAMETERS FOR MATCHED RF OUTPUT ( $V_{CC} = V_{PS} = V_{RFout} = 3.0\text{ V}$ ) –ON EVALUATION BOARD–**  
**( $S_{22}$  data are monitored at RF connector on board)**

2.4 GHz (matched in test circuit 3)

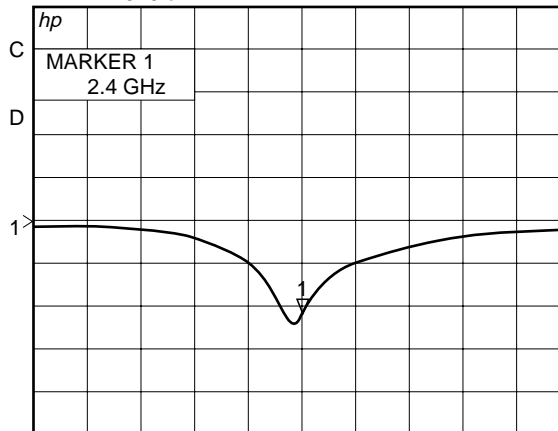
$S_{22}$  Z  
REF 1.0 Units  
1 200.0 mUnits/  
∇ 47.975 Ω -7.1113 Ω  
hp

C MARKER 1  
D 2.4 GHz



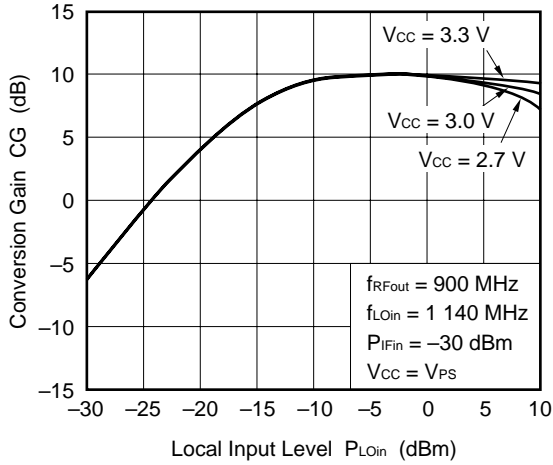
START 1.900000000 GHz  
STOP 2.900000000 GHz

$S_{22}$  log MAG.  
REF 0.0 dB  
1 10.0 dB/  
∇ -22.326 dB  
hp

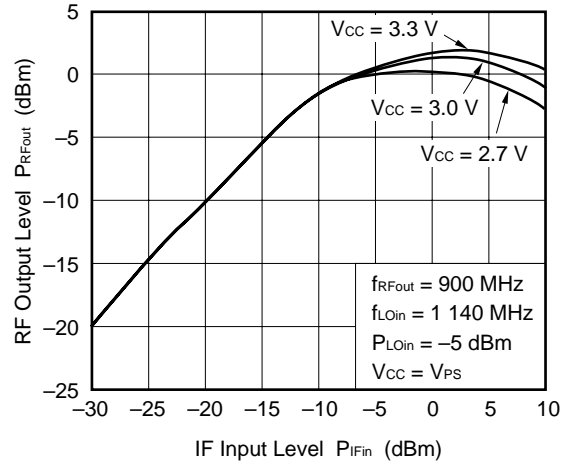


START 1.900000000 GHz  
STOP 2.900000000 GHz

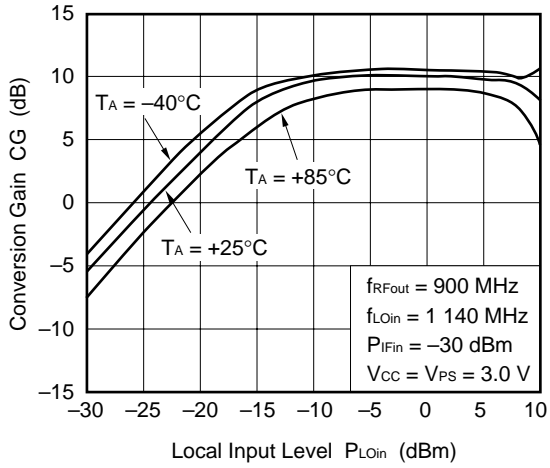
CONVERSION GAIN vs. LOCAL INPUT LEVEL



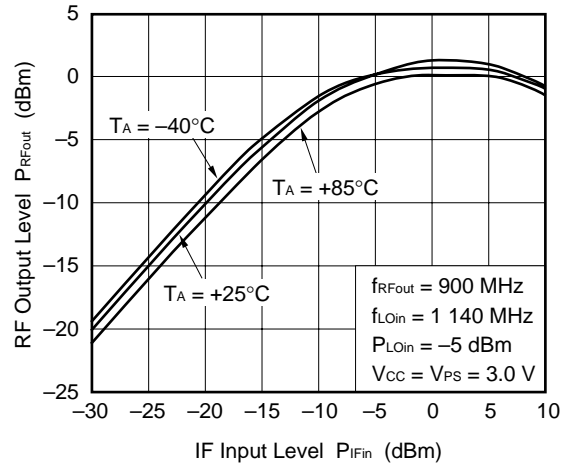
RF OUTPUT LEVEL vs. IF INPUT LEVEL

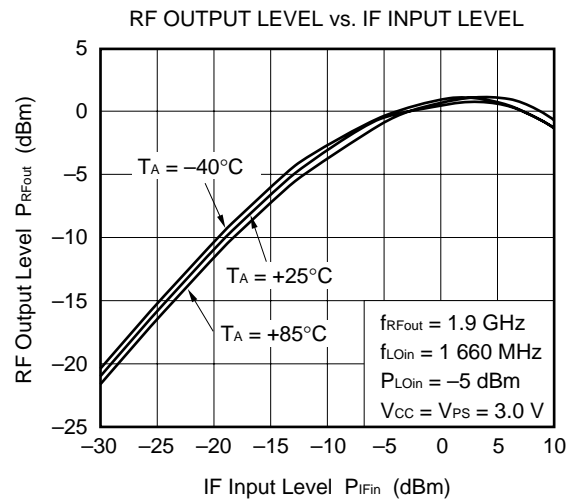
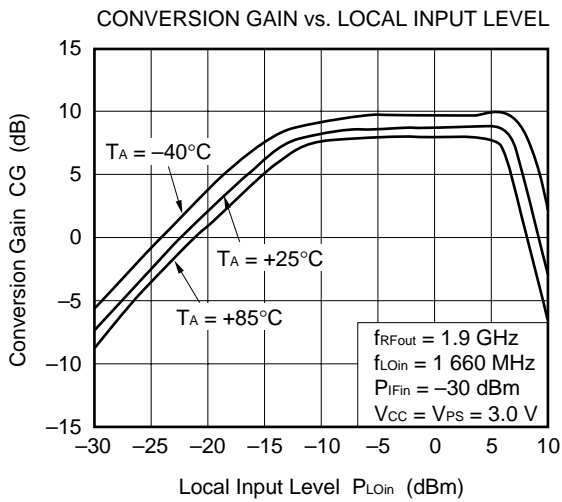
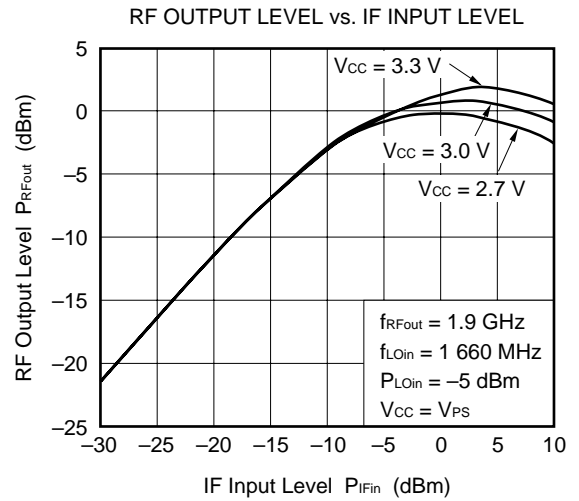
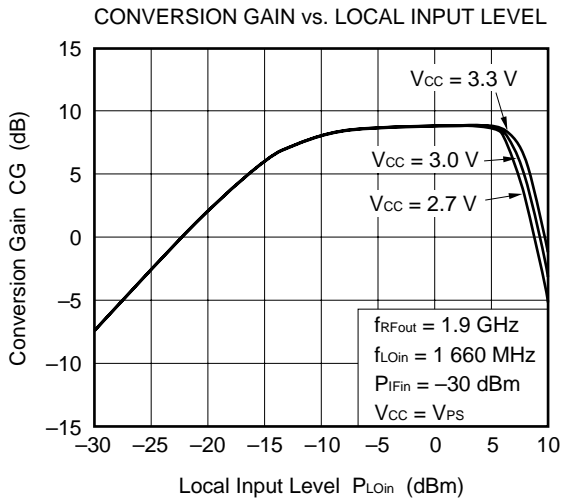


CONVERSION GAIN vs. LOCAL INPUT LEVEL

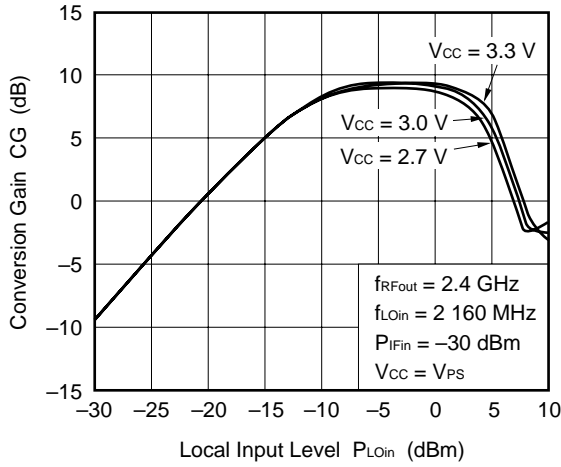


RF OUTPUT LEVEL vs. IF INPUT LEVEL

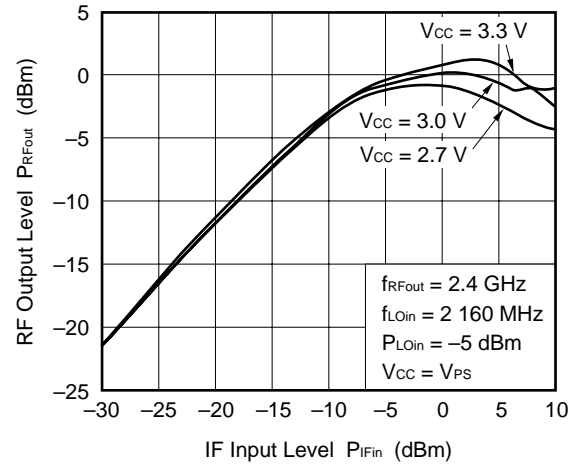




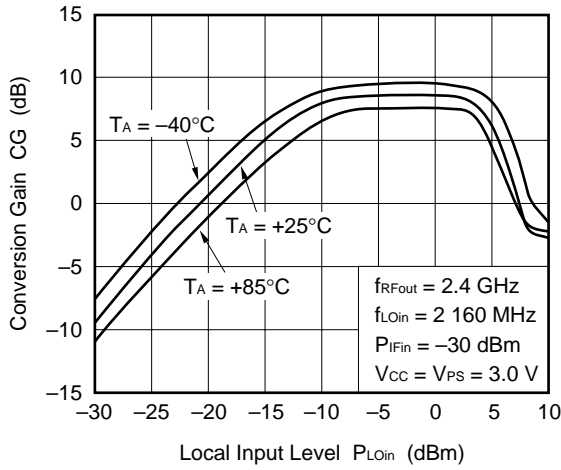
CONVERSION GAIN vs. LOCAL INPUT LEVEL



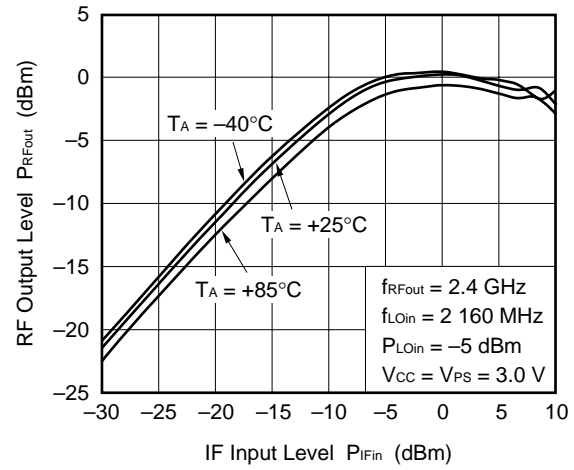
RF OUTPUT LEVEL vs. IF INPUT LEVEL

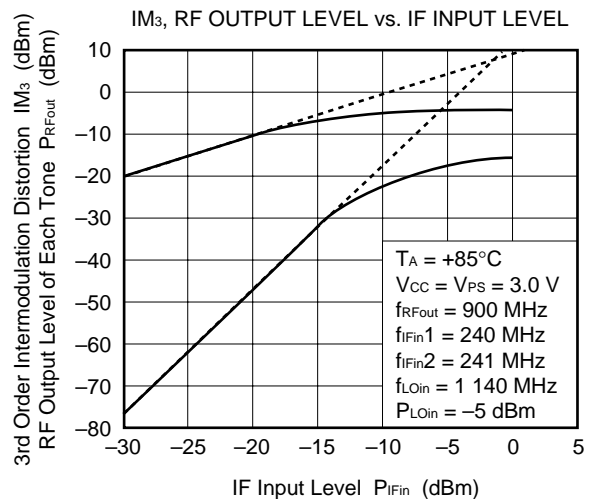
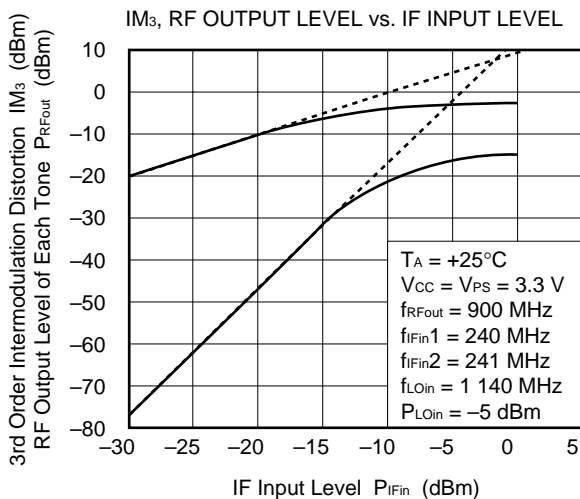
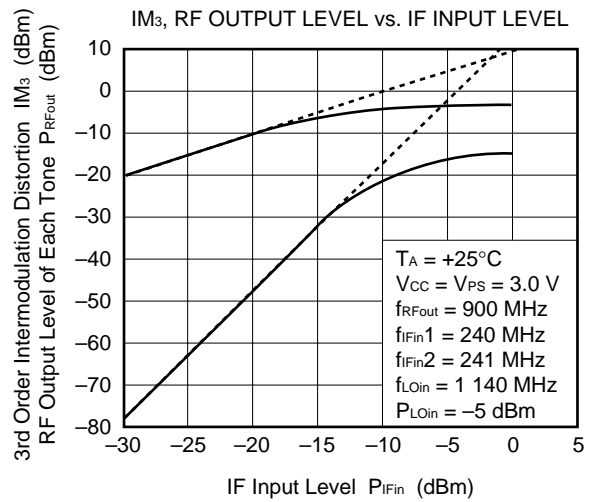
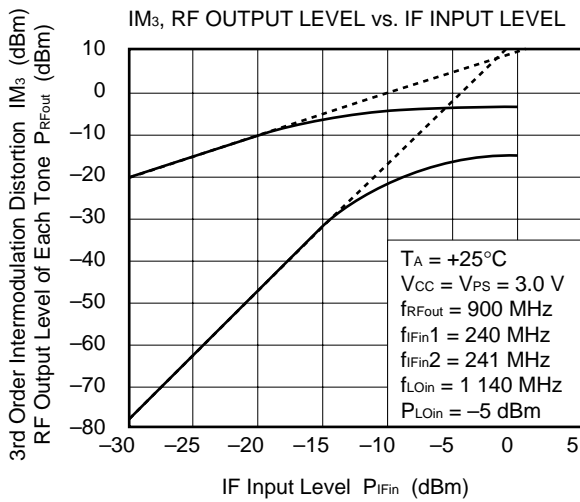
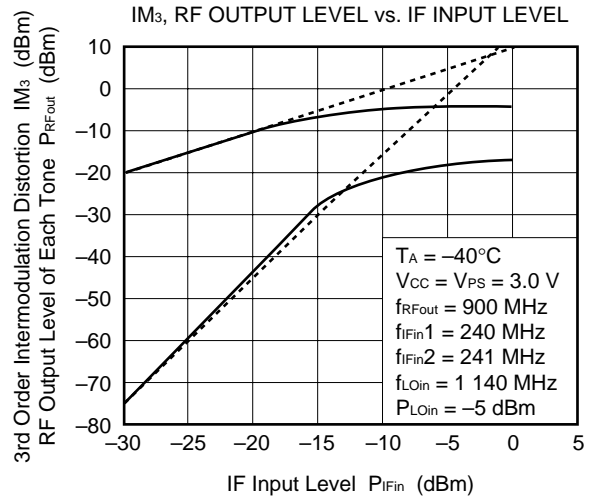
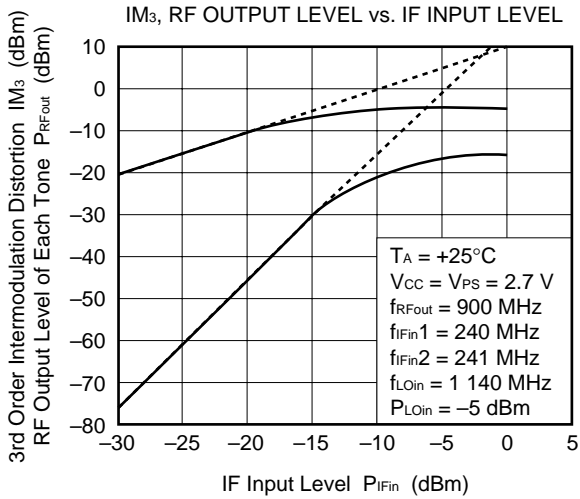


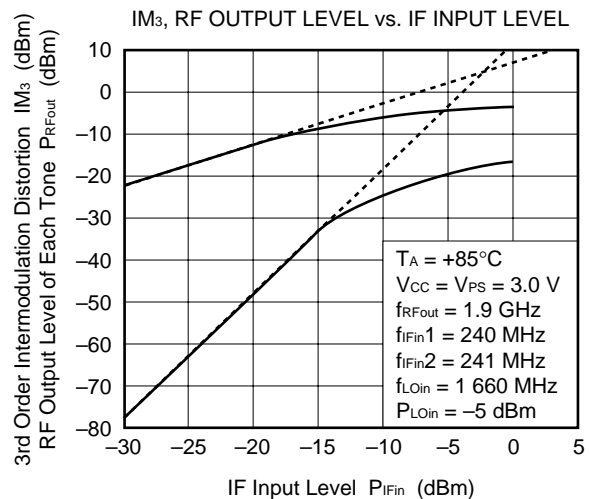
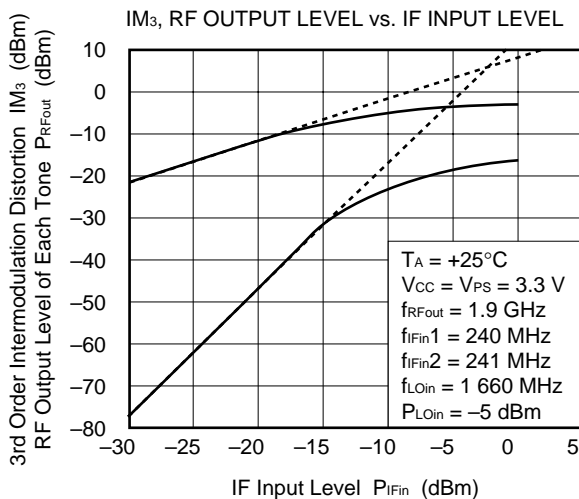
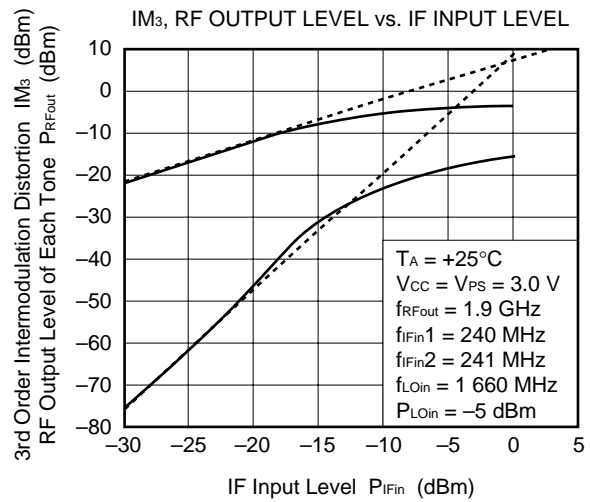
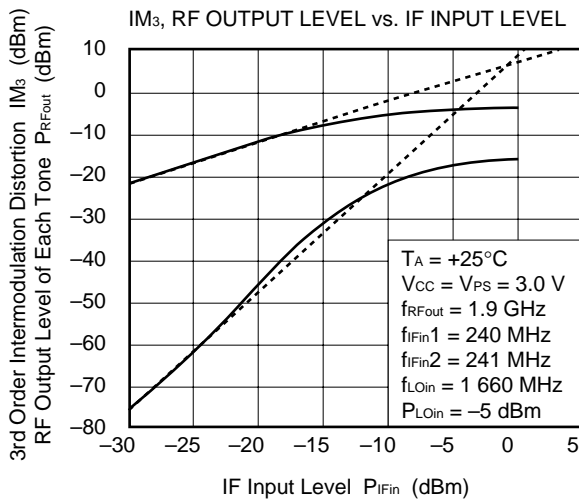
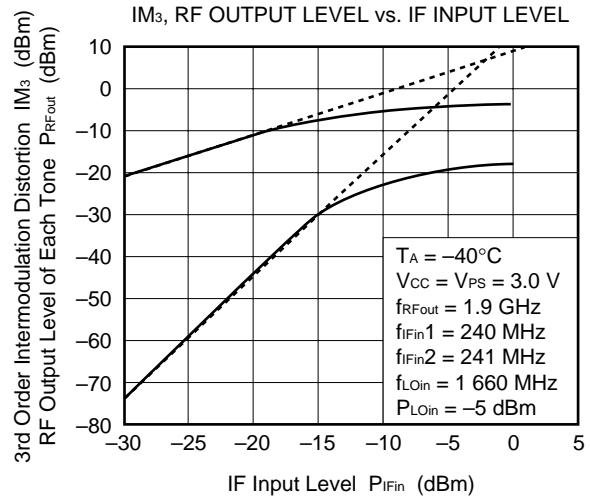
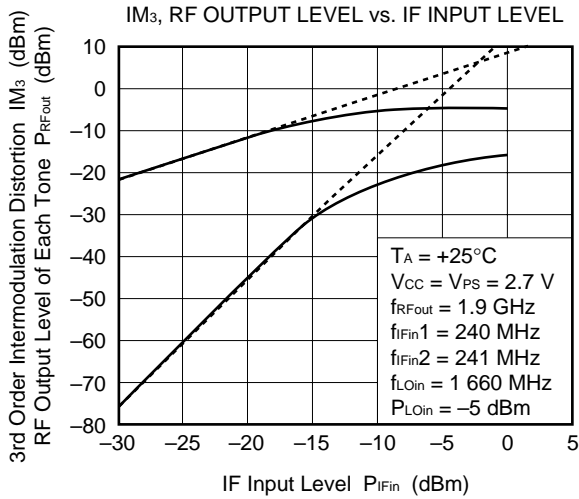
CONVERSION GAIN vs. LOCAL INPUT LEVEL

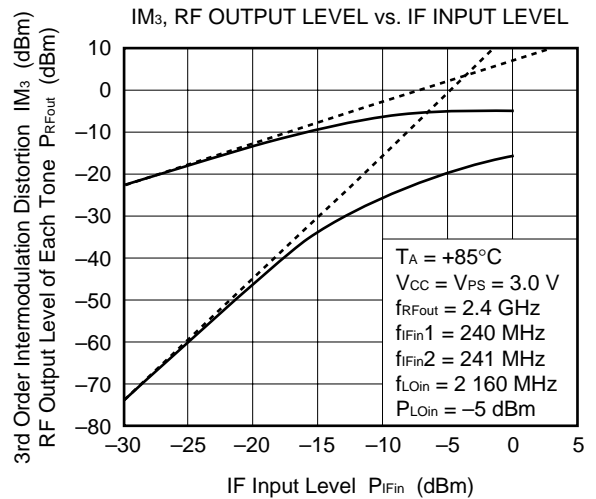
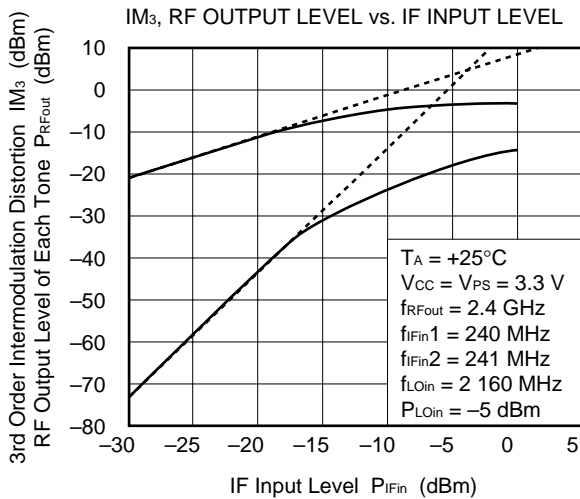
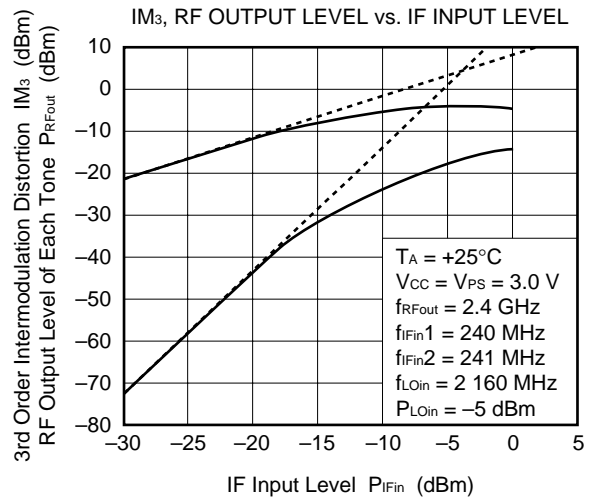
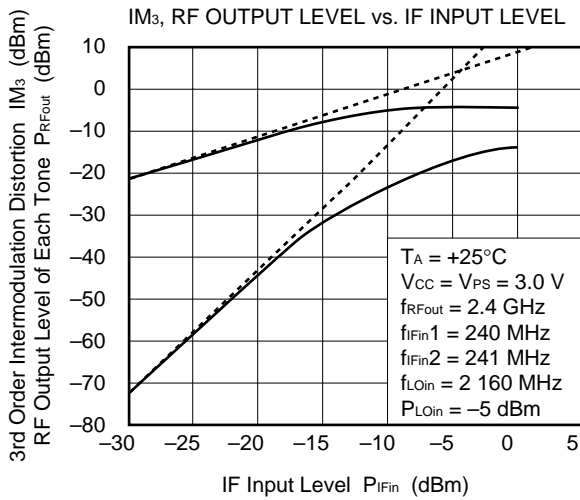
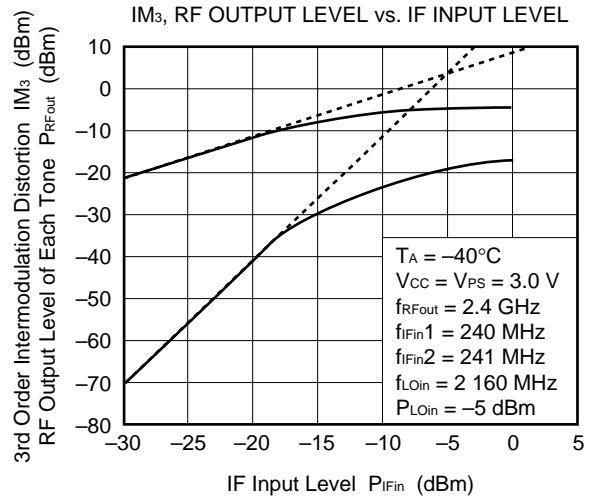
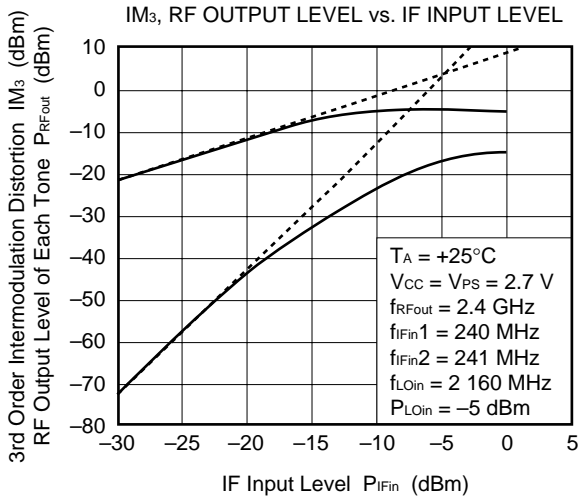


RF OUTPUT LEVEL vs. IF INPUT LEVEL

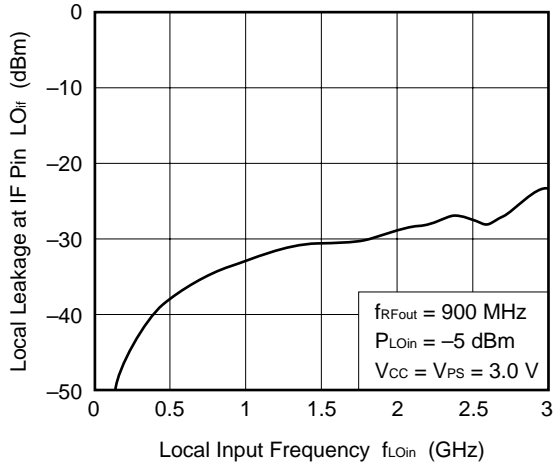




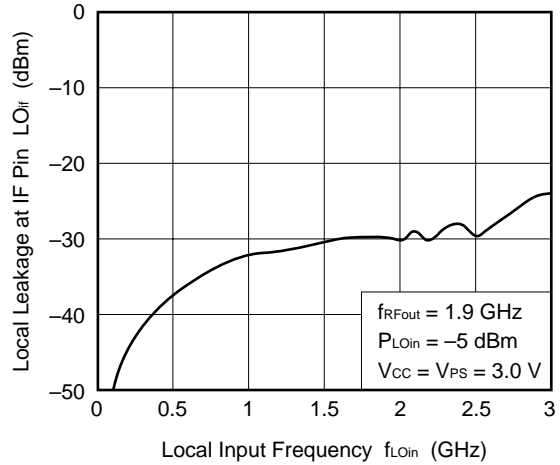




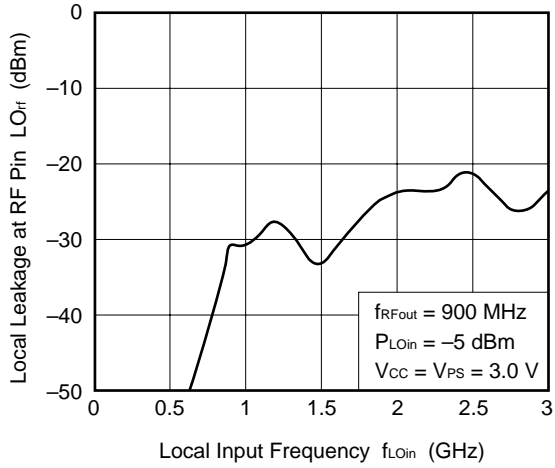
LOCAL LEAKAGE AT IF PIN vs.  
LOCAL INPUT FREQUENCY



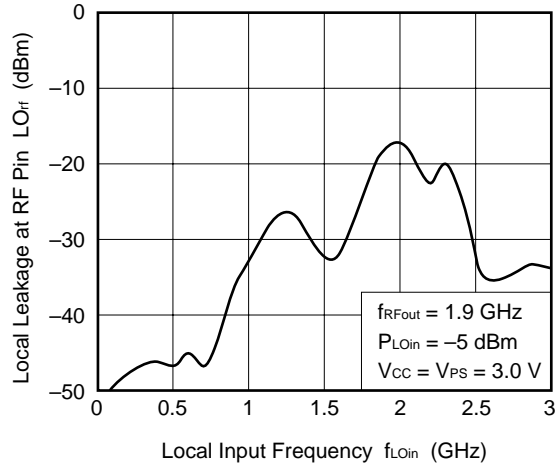
LOCAL LEAKAGE AT IF PIN vs.  
LOCAL INPUT FREQUENCY



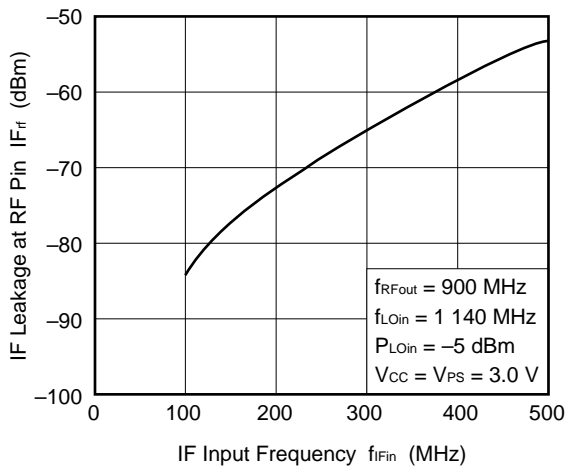
LOCAL LEAKAGE AT RF PIN vs.  
LOCAL INPUT FREQUENCY



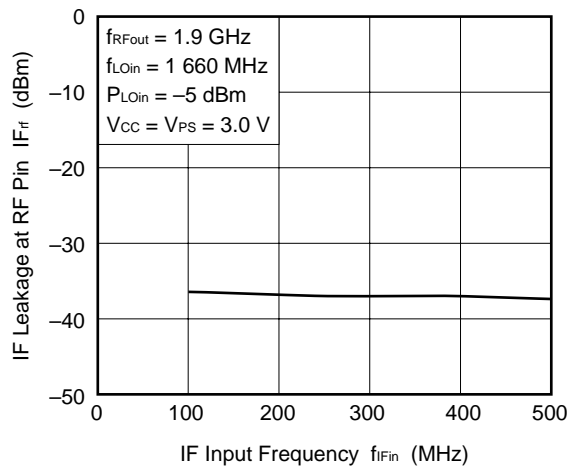
LOCAL LEAKAGE AT RF PIN vs.  
LOCAL INPUT FREQUENCY



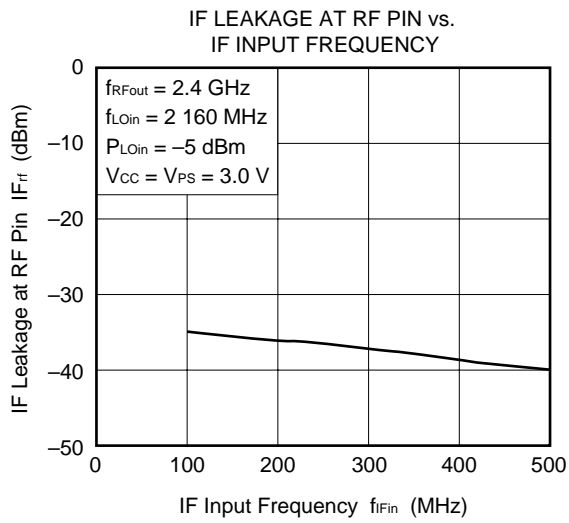
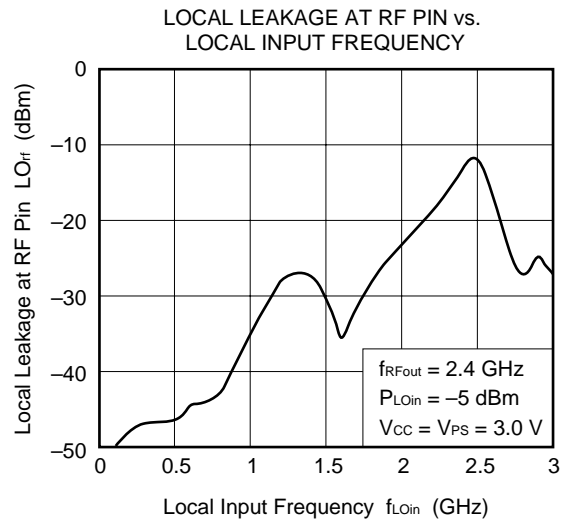
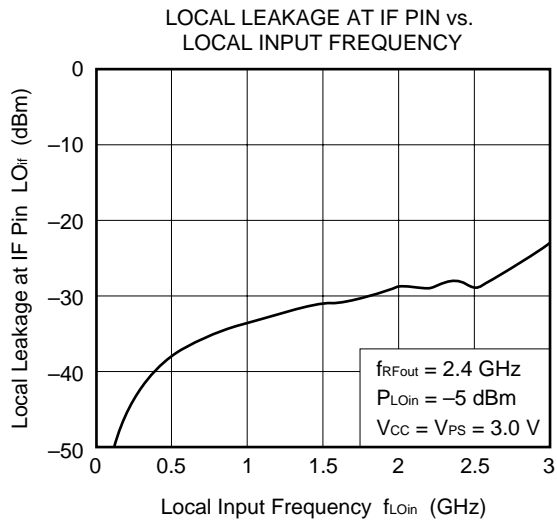
IF LEAKAGE AT RF PIN vs.  
IF INPUT FREQUENCY



IF LEAKAGE AT RF PIN vs.  
IF INPUT FREQUENCY



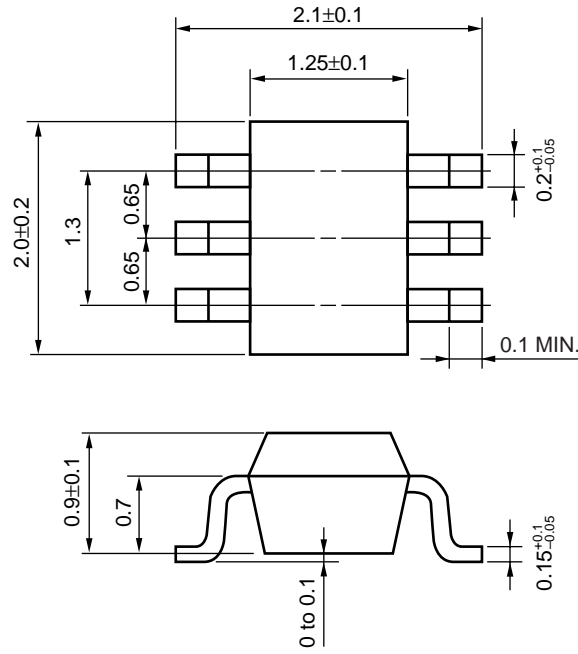




**Remark** The graphs indicate nominal characteristics.

★ 8. PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



**9. NOTE ON CORRECT USE**

- (1) Observe precautions for handling because of electrostatic sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired oscillation).
- (3) Connect a bypass capacitor (example: 1 000 pF) to the V<sub>CC</sub> pin.
- (4) Connect a matching circuit to the RF output pin.
- (5) The DC cut capacitor must be each attached to the input and output pins.

**10. RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit: None <sup>Note</sup>	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit: None <sup>Note</sup>	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit: None <sup>Note</sup>	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit: None <sup>Note</sup>	—

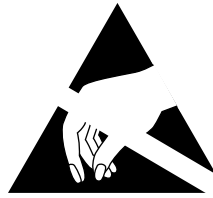
**Note** After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

**Caution** Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]

[MEMO]



## ATTENTION

OBSERVE PRECAUTIONS  
FOR HANDLING  
ELECTROSTATIC  
SENSITIVE  
DEVICES

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